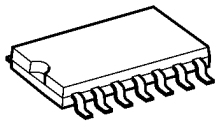
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT125AF, TC74VHCT125AFK
TC74VHCT126AF, TC74VHCT126AFK

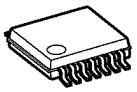
TC74VHCT125AF/AFK Quad Bus Buffer
TC74VHCT126AF/AFK Quad Bus Buffer

TC74VHCT125AF, TC74VHCT126AF



SOP14-P-300-1.27A

TC74VHCT125AFK, TC74VHCT126AFK



VSSOP14-P-0030-0.50

Weight
SOP14-P-300-1.27A : 0.18 g (typ.)
VSSOP14-P-0030-0.50 : 0.02 g (typ.)

The TC74VHCT125A/126A are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCT125A requires the 3-state control input $\overline{G}$ to be set high to place the output into the high impedance state, whereas the TC74VHCT126A requires the control input G to be set low to place the output into high impedance.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. There structure prevents device detsruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

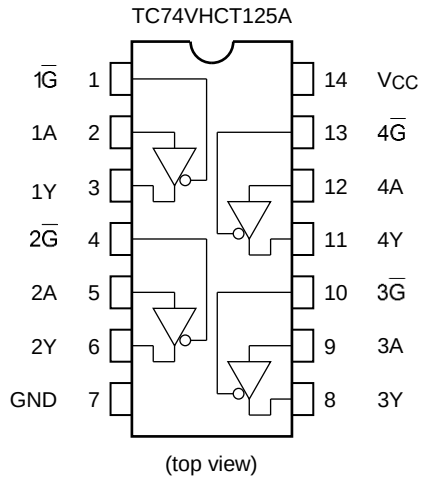
Note: V_{CC} = 0 V

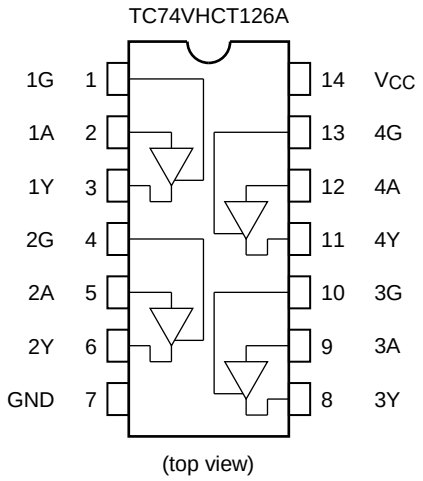
Features

- High speed: t_{pd} = 3.8 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- Compatible with TTL inputs: V_{IL} = 0.8 V (max)
  V_{IH} = 2.0 V (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 125/126 types.

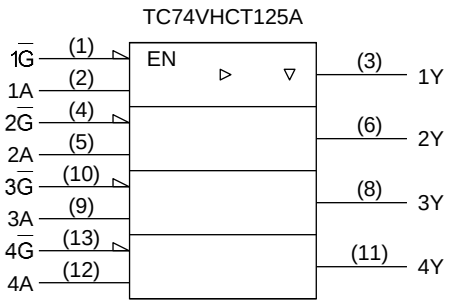
Start of commercial production
1998-02

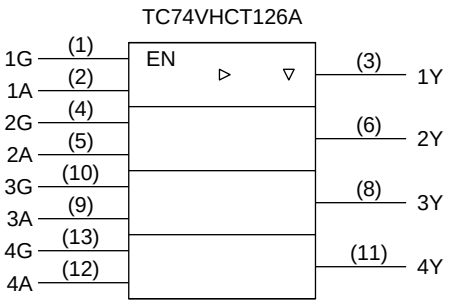
Pin Assignment





IEC Logic Symbol





Truth Table

TC74VHCT125A

Inputs		Output
$\overline{G}$	A	Y
H	X	Z
L	L	L
L	H	H

X: Don’t care

Z: High impedance

TC74VHCT126A

Inputs		Output
G	A	Y
L	X	Z
H	L	L
H	H	H

X: Don’t care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating		Unit
Supply voltage range	V_{CC}	−0.5 to 7.0		V
DC input voltage	V_{IN}	−0.5 to 7.0		V
DC output voltage	V_{OUT}	−0.5 to 7.0	(Note 2)	V
		−0.5 to V_{CC} + 0.5	(Note 3)	
Input diode current	I_{IK}	−20		mA
Output diode current	I_{OK}	±20	(Note 4)	mA
DC output current	I_{OUT}	±25		mA
DC V_{CC}/ground current	I_{CC}	±50		mA
Power dissipation	P_D	180		mW
Storage temperature	T_{stg}	−65 to 150		°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC}

Operating Ranges (Note 1)

Characteristics	Symbol	Rating		Unit
Supply voltage	V_{CC}	4.5 to 5.5		V
Input voltage	V_{IN}	0 to 5.5		V
Output voltage	V_{OUT}	0 to 5.5	(Note 2)	V
		0 to V_{CC}	(Note 3)	
Operating temperature	T_{opr}	−40 to 85		°C
Input rise and fall time	dt/dv	0 to 20		ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Note 2: Output in off-state

Note 3: High or low state

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—	4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V_{IL}	—	4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}, I_{OH} = −50 μA	4.5	4.40	4.50	—	4.40	—	V
		V_{IN} = V_{IH} or V_{IL}, I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}, I_{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
		V_{IN} = V_{IH} or V_{IL}, I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND	0 to 5.5	—	—	±0.1	—	±1.0	μA
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	5.5	—	—	±0.25	—	±2.50	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND	5.5	—	—	4.0	—	40.0	μA
	I_{CCT}	Per input: V_{IN} = 3.4 V Other input: V_{CC} or GND	5.5	—	—	1.35	—	1.50	mA
Output leakage current (Power-OFF)	I_{OPD}	V_{OUT} = 5.5 V	0	—	—	0.5	—	5.0	μA

AC Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	ns
				50	—	5.3	7.5	1.0	8.5	
Output enable time	t_{pZL} t_{pZH}	R_L = 1 kΩ	5.0 ± 0.5	15	—	3.6	5.1	1.0	6.0	ns
				50	—	5.1	7.1	1.0	8.0	
Output disable time	t_{pLZ} t_{pHZ}	R_L = 1 kΩ	5.0 ± 0.5	50	—	6.1	8.8	1.0	10.0	ns
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	5.0 ± 0.5	50	—	—	1.0	—	1.0	ns
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance	C_{PD} (Note 2)	TC74VHCT125A			—	14	—	—	—	pF
		TC74VHCT126A			—	15	—	—	—	

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|,\ t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

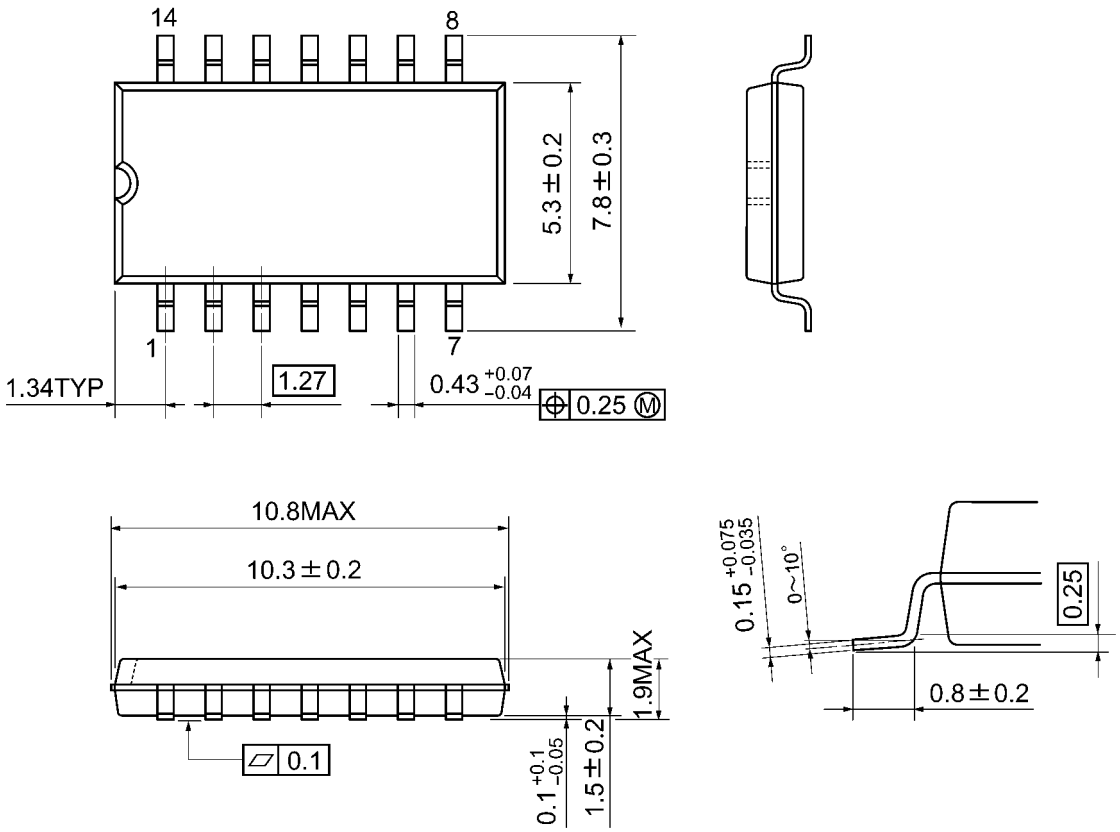
Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.5	−0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	2.0	V
Maximum low level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	0.8	V

Package Dimensions

SOP14-P-300-1.27A

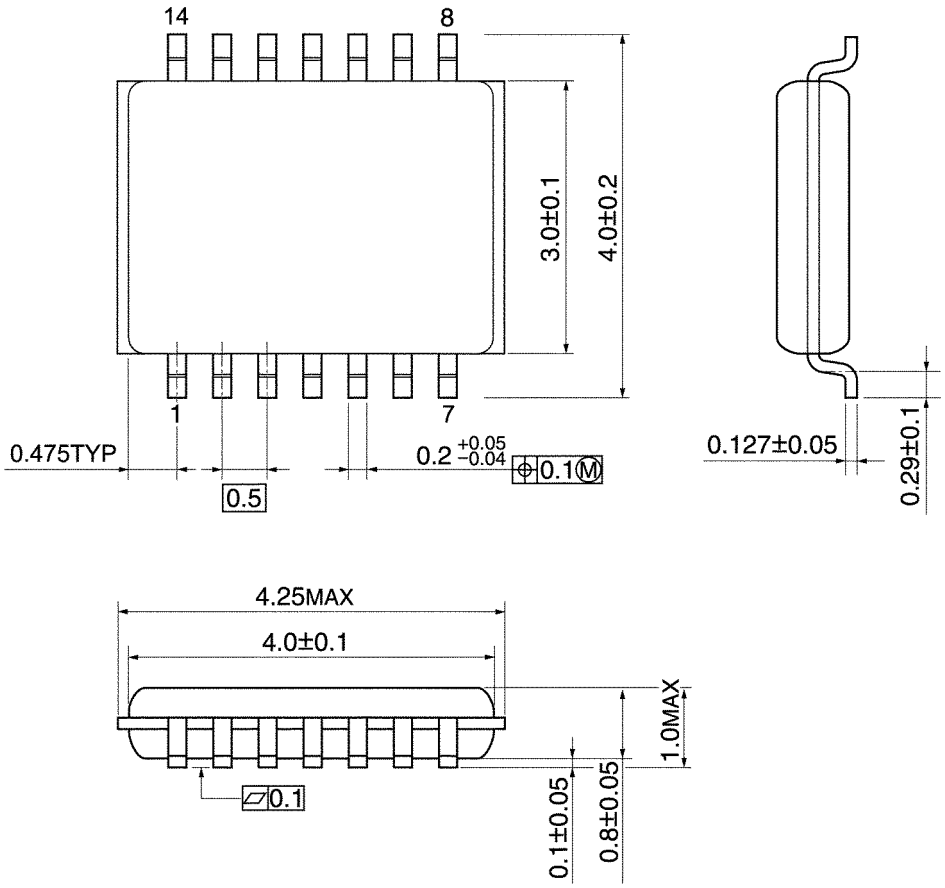
Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)